

SPECIFICATION

Device Name : IGBT Module

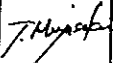
Type Name : 7MBR35SB120-01

Spec. No. : MS6M 0554

Date : Jun. - 02 - 2000

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Matsumoto Factory

	DATE	NAME	APPROVED	Fuji Electric Co., Ltd.			
DRAWN	Jun. - 2 - '00	T. Kobayashi		DWG. NO.	MS6M 0554	1 / 10	Q
CHECKED	June - 2 - 00	S. Matsu					

Revised Records

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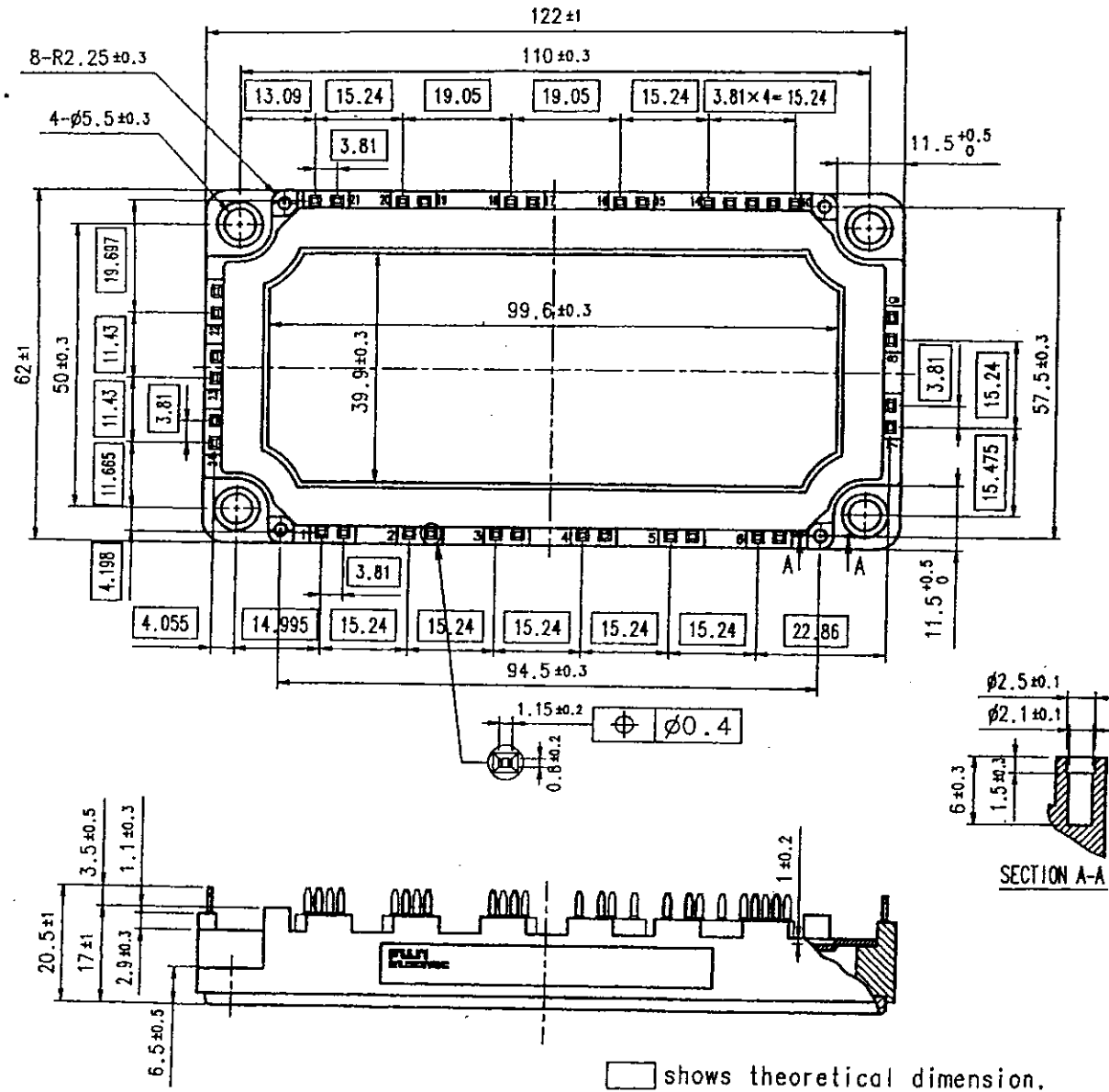
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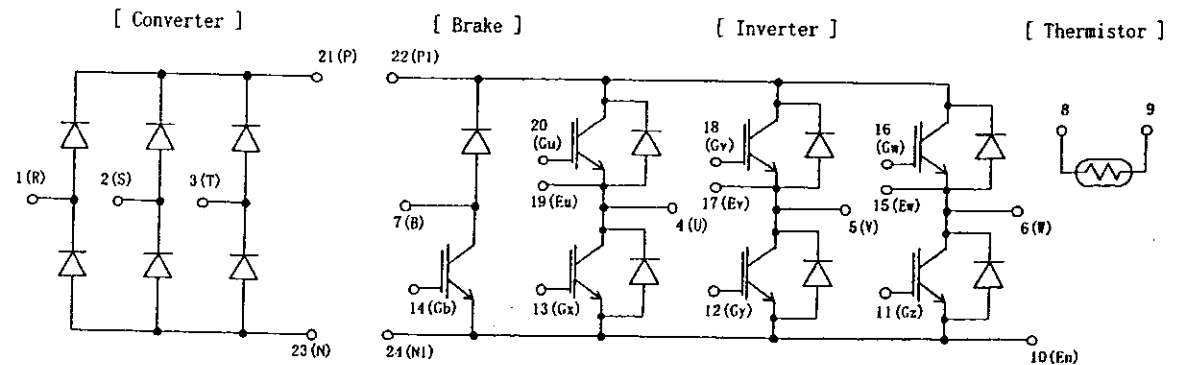
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1. Outline Drawing (Unit : mm)



2. Equivalent circuit



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3. Absolute Maximum Ratings (at Tc= 25C unless otherwise specified)

Items		Symbols	Conditions		Maximum Ratings	Units
Inverter	Collector-Emitter voltage	V _{CES}			1200	V
	Gate-Emitter voltage	V _{GES}			+20	V
	Collector current	I _c	Continuous	T _c =25C	50	A
		T _c =80C		35		
		I _{cp}	1ms	T _c =25C	100	A
				T _c =80C	70	
		-I _c			35	A
Collector Power Dissipation	P _c	1 device		240	W	
Brake	Collector-Emitter voltage	V _{CES}			1200	V
	Gate-Emitter voltage	V _{GES}			+20	V
	Collector current	I _c	Continuous	T _c =25C	35	A
				T _c =80C	25	
		I _{cp}	1ms	T _c =25C	70	A
				T _c =80C	50	
	Collector Power Dissipation	P _c	1 device		180	W
Repetitive peak reverse Voltage(Diode)	V _{RRM}			1200	V	
Converter	Repetitive peak reverse Voltage	V _{RRM}			1600	V
	Average Output Current	I _o	50Hz/60Hz sine wave		35	A
	Surge Current (Non-Repetitive)	I _{FSM}	T _j =150C,10ms		360	A
	I ² _t (Non-Repetitive)	I ² _t	half sine wave		648	A ² s
	Junction temperature	T _j			150	C
Storage temperature		T _{stg}			-40~ +125	C
Isolation voltage	between terminal and copper base ⁽¹⁾	Viso	AC : 1min.		2500	V
	between thermistor and others ⁽²⁾				2500	V
Mounting Screw Torque ⁽³⁾					3.5	Nm

(*1) All terminals should be connected together when isolation test will be done.

(*2) Terminal 8 and 9 should be connected together. Terminal 1 to 7 and 10 to 24 should be connected together and shorted to copper base.

(*3) Recommendable Value : 2.5~3.5 Nm (M5)

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4. Electrical characteristics (at Tj= 25C unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	Max.	
Inverter	Zero gate voltage Collector current	ICES VGE = 0 V, VCE= 1200 V			1.0	mA
	Gate-Emitter leakage current	IGES VCE = 0 V, VGE= +20 V			200	nA
	Gate-Emitter threshold voltage	VGE(th) VCE = 20 V, Ic = 35 mA	5.5	7.2	8.5	V
	Collector-Emitter saturation voltage	VCE(sat) VGE = 15 V, chip		2.1		V
		Ic = 35 A terminal		2.25	2.7	
	Input capacitance	Cies VGE = 0 V, VCE= 10 V f = 1 MHz		4200		pF
	Turn-on time	Vcc= 600 V Ic = 35 A VGE = +15 V		0.35	1.2	us
				0.25	0.6	
				0.1		
	Turn-off time	RG = 33 ohm		0.45	1.0	
				0.08	0.3	
	Forward on voltage	VF IF = 35 A chip		2.3		V
				2.45	3.3	
	Reverse recovery time	trr IF = 35 A			350	ns
Brake	Zero gate voltage Collector current	ICES VGE = 0 V, VCE= 1200 V			1.0	mA
	Gate-Emitter leakage current	IGES VCE = 0 V, VGE= +20 V			200	nA
	Collector-Emitter saturation voltage	VCE(sat) VGE = 15 V, chip		2.1		V
		Ic = 25 A terminal		2.25	2.7	
	Turn-on time	Vcc= 600 V Ic = 25 A		0.35	1.2	us
				0.25	0.6	
	Turn-off time	VGE = +15 V RG = 51 ohm		0.45	1.0	
				0.08	0.3	
Converter	Forward on voltage	VFM IF = 35 A chip		1.1		V
	Reverse current	IRRM VR = 1600 V		1.2	1.5	
Thermistor	Resistance	R T = 25C		5000		ohm
		T = 100C	465	495	520	
	B value	B T = 25/50C	3305	3375	3450	K

5. Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	Max.	
Thermal resistance (1 device)	Rth(j-c)	Inverter IGBT			0.52	C/W
		Inverter FWD			0.90	
		Brake IGBT			0.69	
		Converter Diode			0.75	
Contact Thermal resistance	Rth(c-f)	with Thermal Compound (*)		0.05		C/W

* This is the value which is defined mounting on the additional cooling fin with thermal compound.

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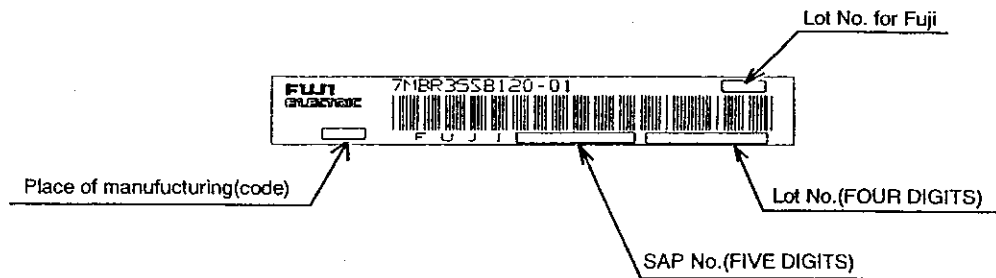
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6. Indication on module



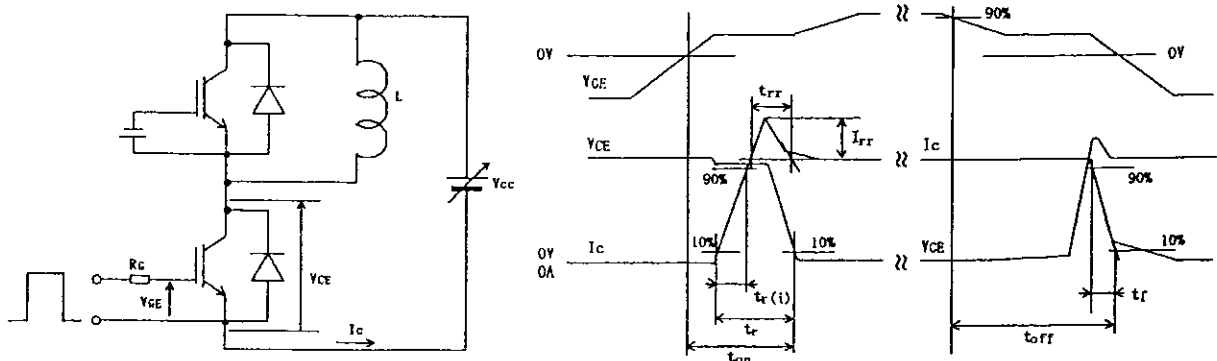
7. Applicable category

This specification is applied to Power Integrated Module named 7MBR35SB120-01 .

8. Storage and transportation notes

- The module should be stored at a standard temperature of 5 to 35°C and humidity of 45 to 75% .
- Store modules in a place with few temperature changes in order to avoid condensation on the module surface.
- Avoid exposure to corrosive gases and dust.
- Avoid excessive external force on the module.
- Store modules with unprocessed terminals.
- Do not drop or otherwise shock the modules when transporting.
- Please connect adequate fuse or protector of circuit between three-phase line and this product to prevent the equipment from causing secondary destruction.

9. Definitions of switching time



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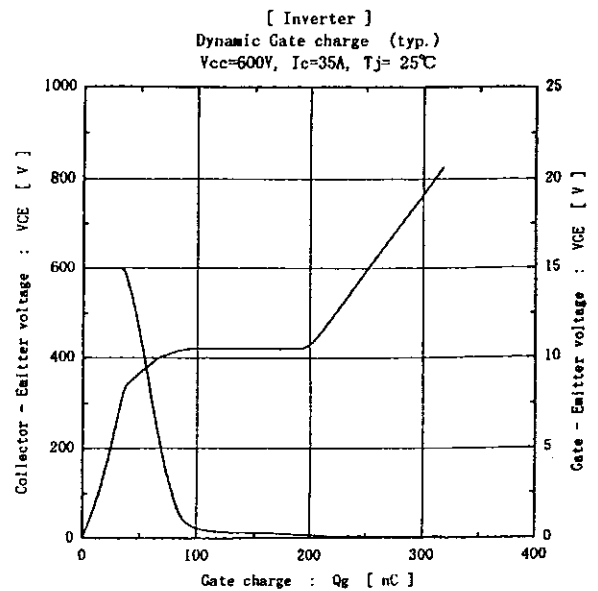
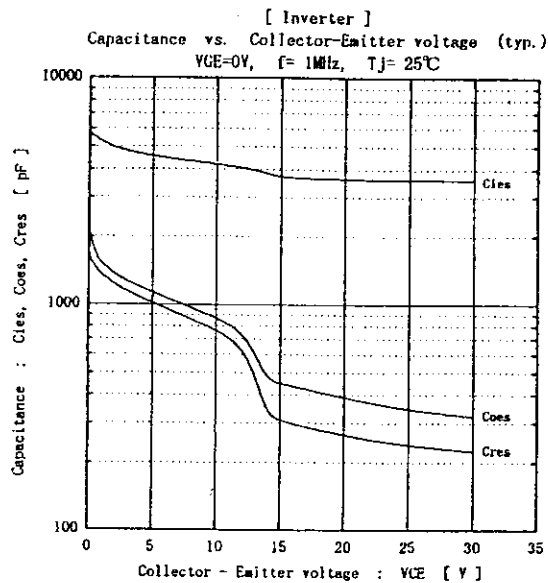
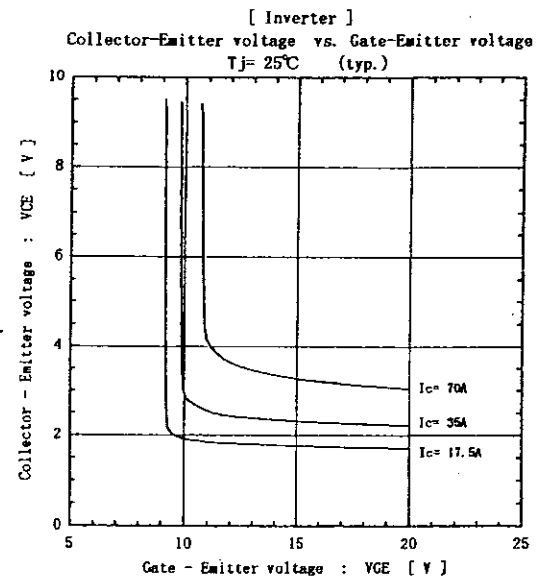
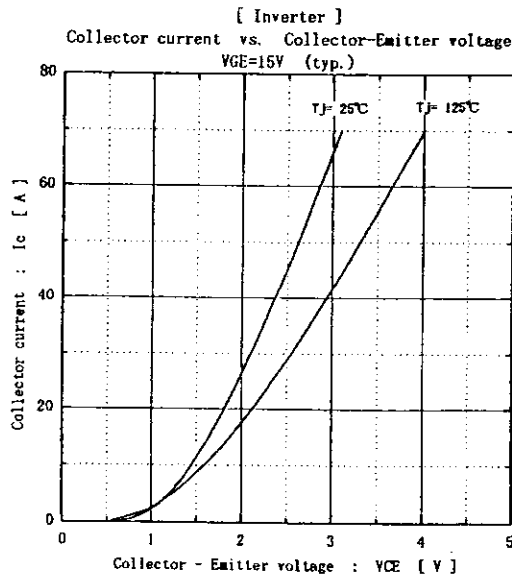
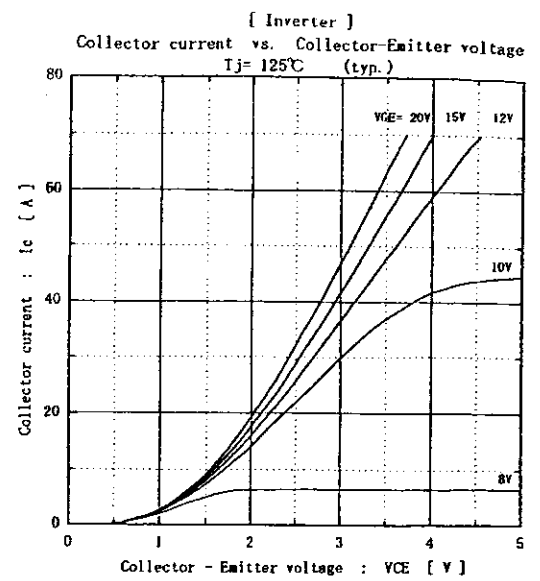
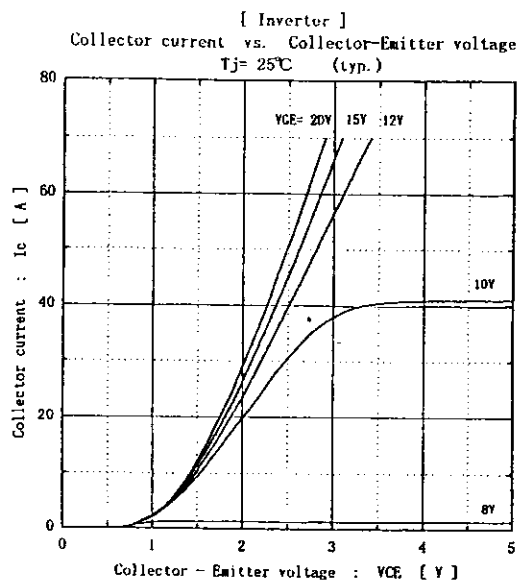
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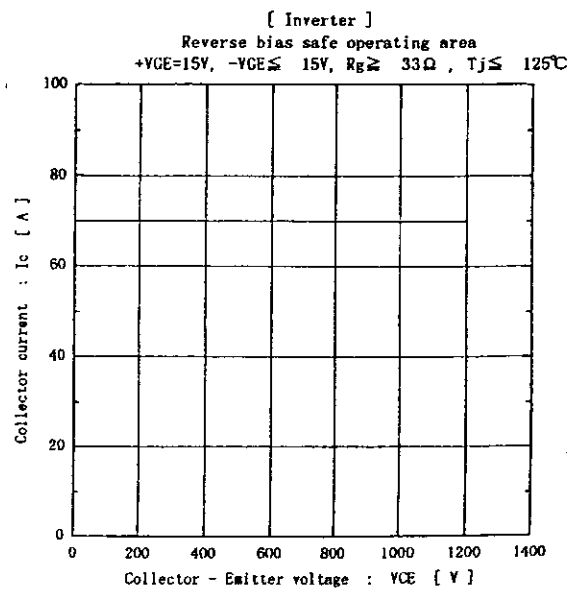
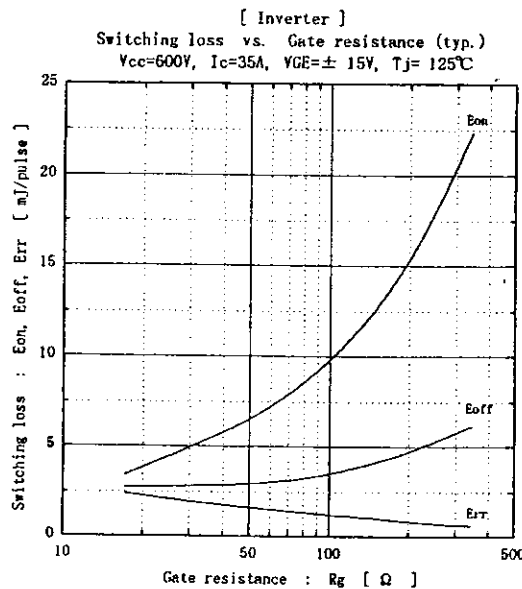
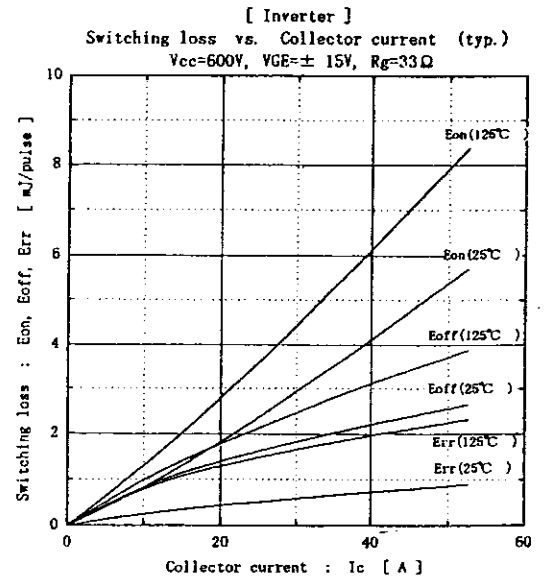
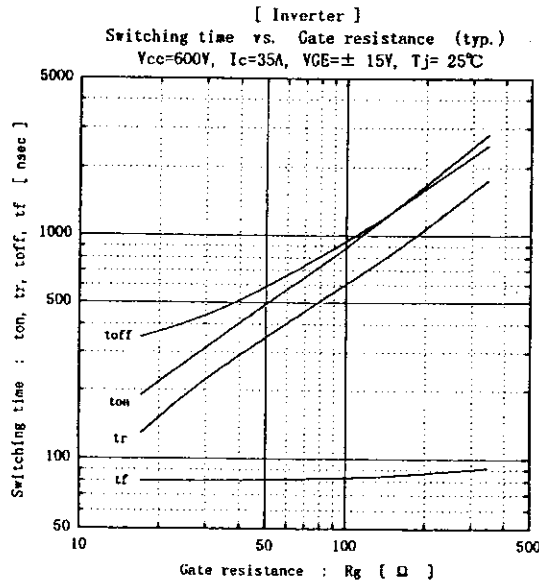
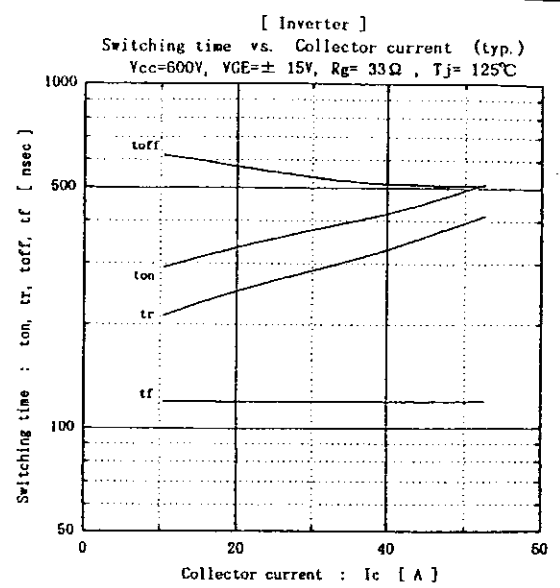
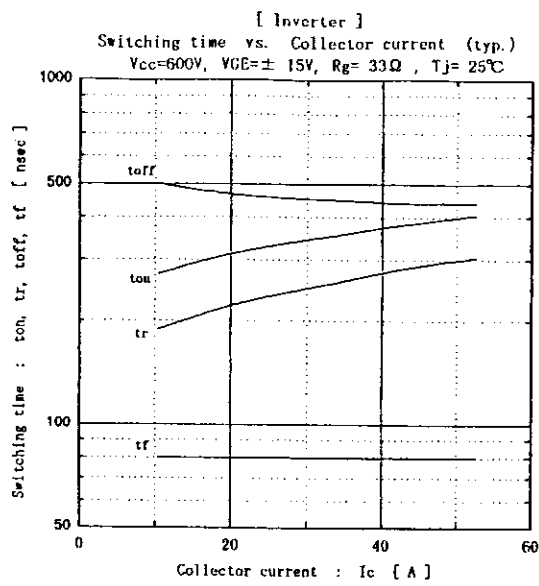
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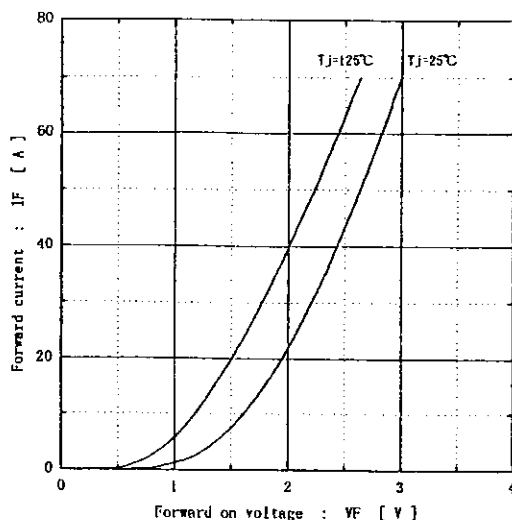
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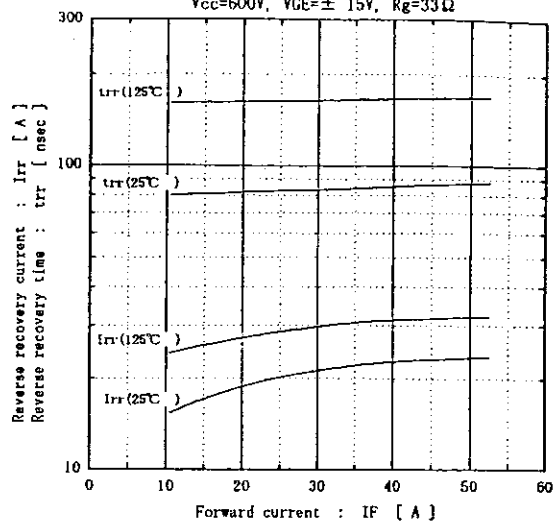
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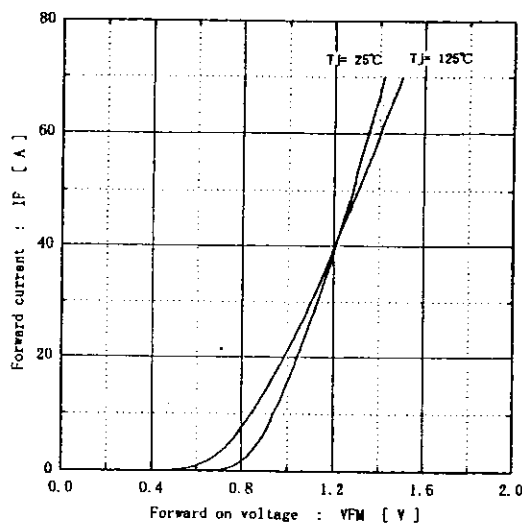
[Inverter]
Forward current vs. Forward on voltage (typ.)



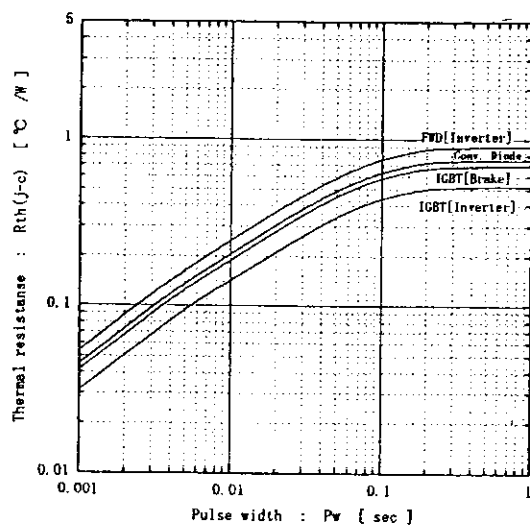
[Inverter]
Reverse recovery characteristics (typ.)
 $V_{CC}=600\text{V}$, $V_{GE}=\pm 15\text{V}$, $R_g=33\Omega$



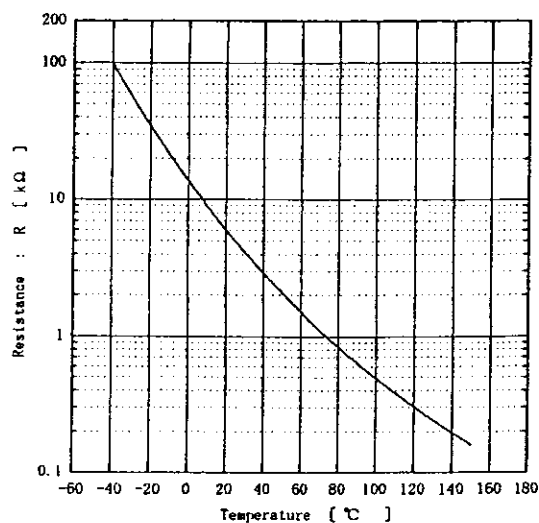
[Converter]
Forward current vs. Forward on voltage (typ.)



Transient thermal resistance



[Thermistor]
Temperature characteristic (typ.)



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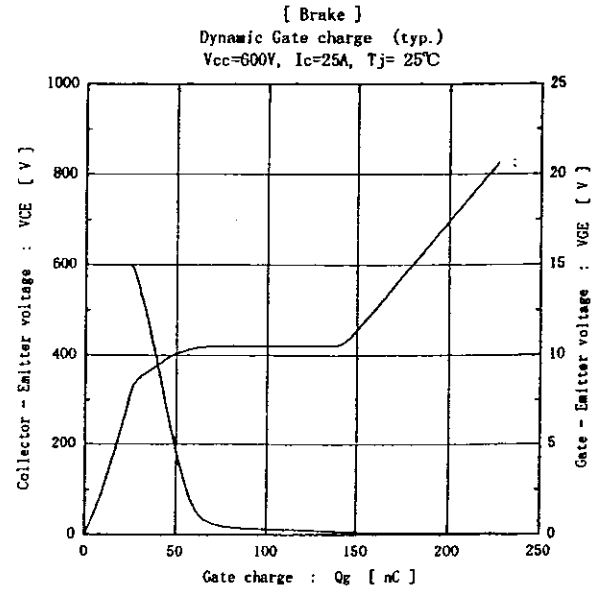
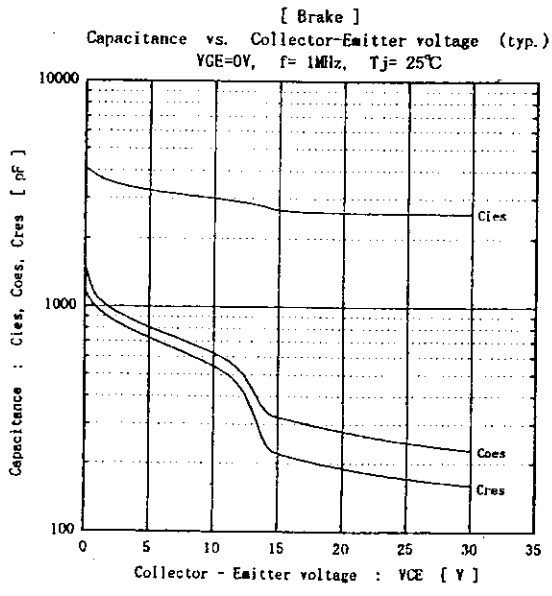
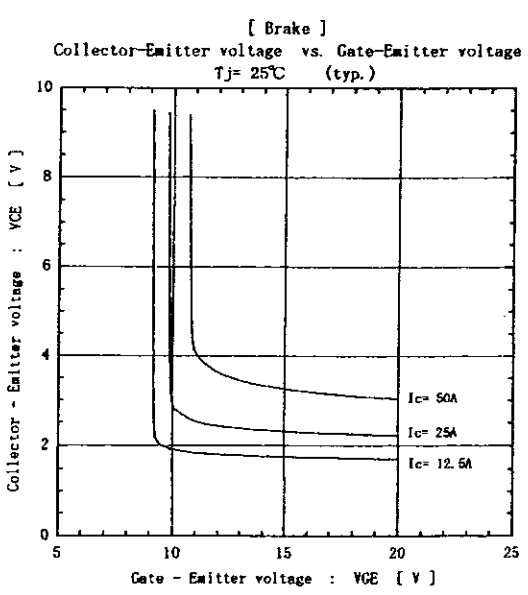
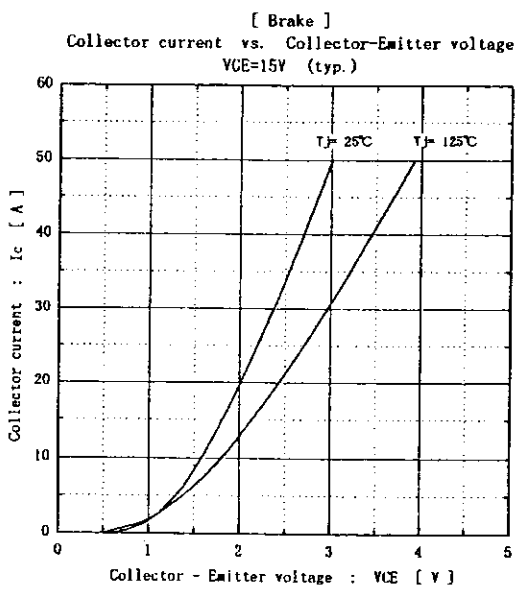
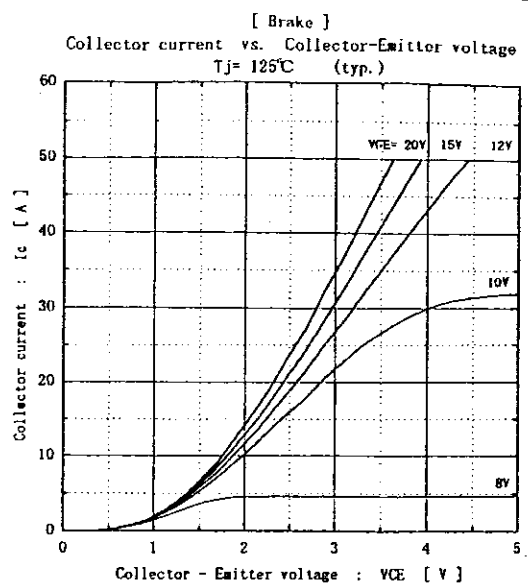
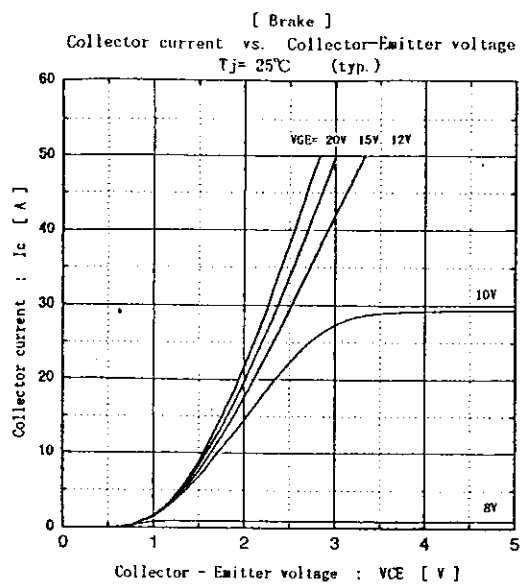
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